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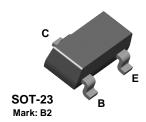
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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild <a href="general-regarding-numbers-n

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BSV52



NPN Switching Transistor

This device is designed for high speed saturated switching at collector currents of 10 mA to 100 mA. Sourced from Process 21.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------------------------------|--|-------------|-------|
| V_{CEO} | Collector-Emitter Voltage | 12 | V |
| V _{CES} | Collector-Base Voltage | 20 | V |
| V_{EBO} | Emitter-Base Voltage | 5.0 | V |
| Ic | Collector Current - Continuous | 200 | mA |
| T _J , T _{stg} | Operating and Storage Junction Temperature Range | -55 to +150 | °C |

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

| Symbol | Characteristic | Max | Units |
|-----------------|---|--------|-------|
| | | *BSV52 | |
| P _D | Total Device Dissipation | 225 | mW |
| | Derate above 25°C | 1.8 | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 556 | °C/W |

^{*}Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

(continued)

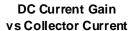
| Symbol | Parameter | Test Conditions | Min | Max | Units |
|----------------------|--------------------------------------|---|-----|----------|----------|
| | | | | | |
| OFF CHA | RACTERISTICS | | | | |
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | $I_C = 10 \text{ mA}, I_B = 0$ | 12 | | V |
| V _{(BR)CES} | Collector-Base Breakdown Voltage | $I_C = 10 \mu A, I_E = 0$ | 20 | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | $I_E = 100 \mu A, I_C = 0$ | 5.0 | | V |
| I _{CBO} | Collector-Cutoff Current | $V_{CB} = 10 \text{ V}, I_{E} = 0$ | | 100 | nA |
| | | $V_{CB} = 10 \text{ V}, I_E = 0, T_A = 125^{\circ}\text{C}$ | | 5.0 | μΑ |
| | | | | | |
| | ACTERISTICS | | | | |
| | DC Current Gain | 1 10 10 1/ | 25 | | |
| h _{FE} | DC Current Gain | $I_C = 1.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$ | 40 | 120 | |
| | | $I_{\rm C} = 50 \text{mA}, V_{\rm CE} = 1.0 \text{V}$ | 25 | 120 | |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 10 mA, I _B = 0.3 mA | | 0.3 | V |
| () | _ | $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ | | 0.25 | V |
| | | $I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$ | | 0.4 | V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$ | 0.7 | 0.85 | V |
| | | $I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$ | | 1.2 | V |
| | | | | | |
| SMALL SI | GNAL CHARACTERISTICS | | | | |
| f _T | Transition Frequency | $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 10 V, | 400 | | MHz |
| ΙŢ | Transition Frequency | f = 100 MHz | 400 | | IVII IZ |
| C _{cb} | Collector-Base Capacitance | I _E = 0, V _{CB} = 5.0 V, f = 1.0 MHz | | 4.0 | pF |
| C _{eb} | Emitter-Base Capacitance | $I_C = 0$, $V_{EB} = 1.0 \text{ V}$, $f = 1.0 \text{ MHz}$ | | 4.5 | pF |
| | · | | | | |
| | | | | | |
| | | | | | |
| SWITCHIN | NG CHARACTERISTICS | | | | |
| SWITCHIN | NG CHARACTERISTICS Storage Time | $I_{B1} = I_{B2} = I_C = 10 \text{ mA}$ | | 13 | ns |
| | | $I_{B1} = I_{B2} = I_C = 10 \text{ mA}$ $V_{CC} = 3.0 \text{ V}, I_C = 10 \text{ mA},$ | | 13 12 | ns ns |
| ts | Storage Time | | | | |
| ts | Storage Time | $V_{CC} = 3.0 \text{ V}, I_{C} = 10 \text{ mA},$ | | | _ |

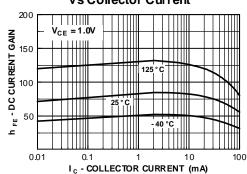
Spice Model

 $NPN \ (Is=44.14f \ Xti=3 \ Eg=1.11 \ Vaf=100 \ Bf=78.32 \ Ne=1.389 \ Ise=91.95f \ Ikf=.3498 \ Xtb=1.5 \ Br=12.69m \ Nc=2 \ Isc=0 \ Ikr=0 \ Rc=.6 \ Cjc=2.83p \ Mjc=86.19m \ Vjc=.75 \ Fc=.5 \ Cje=4.5p \ Mje=.2418 \ Vje=.75 \ Tr=1.073u \ Tf=227.6p \ Itf=.3 \ Vtf=4 \ Xtf=4 \ Rb=10)$

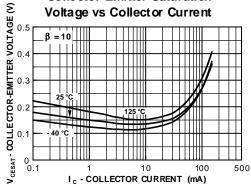
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Typical Characteristics

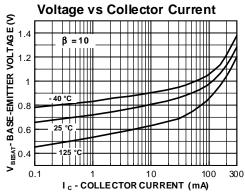




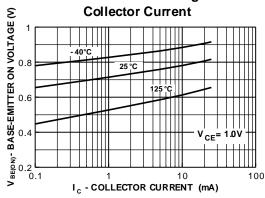
Collector-Emitter Saturation Voltage vs Collector Current



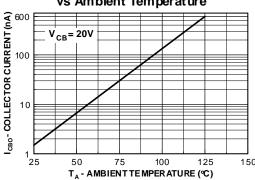
Base-Emitter Saturation



Base-Emitter ON Voltage vs

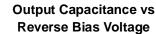


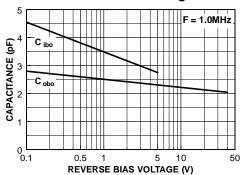
Collector-Cutoff Current vs Ambient Temperature



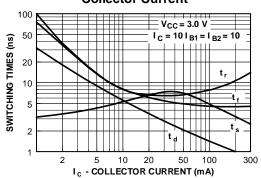
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Typical Characteristics (continued)

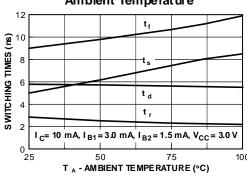




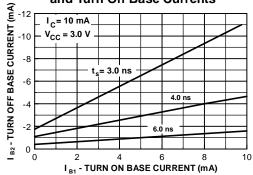
Switching Times vs Collector Current



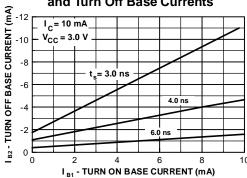
Switching Times vs Ambient Temperature



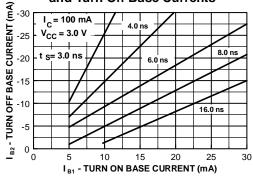
Storage Time vs Turn On and Turn Off Base Currents



Storage Time vs Turn On and Turn Off Base Currents

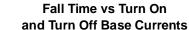


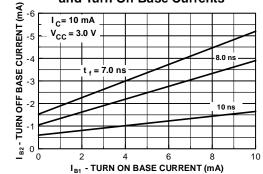
Storage Time vs Turn On and Turn Off Base Currents



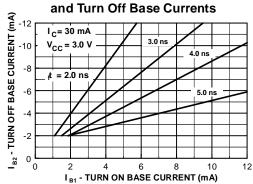
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Typical Characteristics (continued)

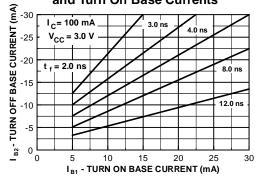




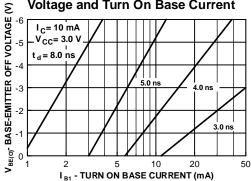
Fall Time vs Turn On



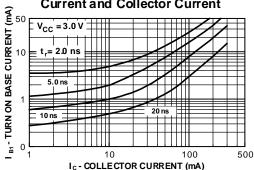
Fall Time vs Turn On and Turn Off Base Currents



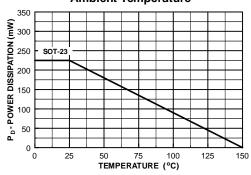
Delay Time vs Base-Emitter OFF Voltage and Turn On Base Current



Rise Time vs. Turn On Base Current and Collector Current



Power Dissipation vs Ambient Temperature



(continued)

Test Circuits

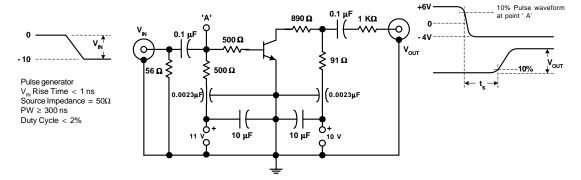


FIGURE 1: Charge Storage Time Measurement Circuit

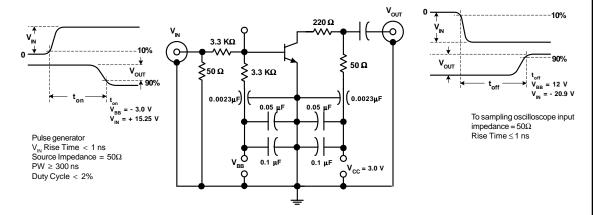


FIGURE 2: $\mathbf{t}_{\text{ON}}, \mathbf{t}_{\text{OFF}}$ Measurement Circuit

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